

PCI Express Gen II, 2-lane (4-channel), Differential Mux/Demux with Bypass

Features

- 8 Differential Channel SPST switch with Mux/DeMux option
- PCI Express Gen II performance
- Low Bit-to-Bit Skew: 10ps (between +/- signals)
- Low Crosstalk: -35dB @ 3.0 GHz
- Low Off Isolation: -26db @ 3.0 GHz
- VCC Operating Range: +1.5V to +2.0V
- ESD Tolerance >2kV HBM
- Packaging (Pb-free & Green): 42-contact TQFN (ZH42)

Description

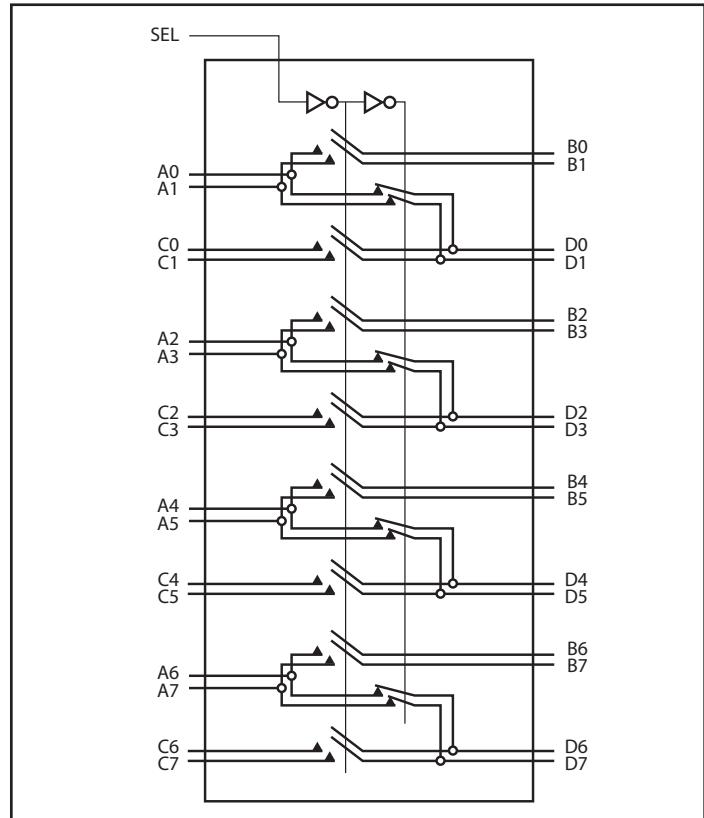
Pericom semiconductor's PI2PCIE2422 is an 8 to 4 channel differential multiplexer/demultiplexer featuring 8-channel pass-through. It supports two full PCI Express lanes at 5.0Gbps Gen II performance.

With the select control input low Port A connects to Port B, and Port C connects to port D for an 8-channel differential pass-through. When the select control input is high Port A connects to Port D, and Port B and Port C are in a high-impedance state. The mux/demux function is between Port A and Ports B or D as determined by the select input control.

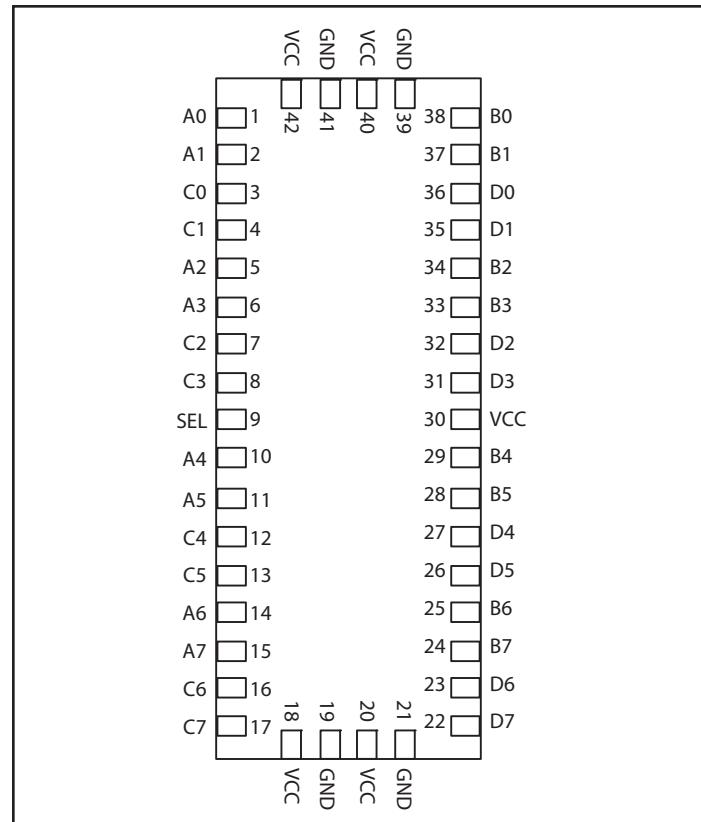
Truth Table

Function	SEL
Ax = Bx Cx = Dx	L
Ax = Dx B = C = Hi-Z	H

Block Diagram



Pin Diagram



Pin Description

Pin #	Pin Name	I/O	Description
1, 2	A0, A1	I/O	Signal I/O (typically a differential pair)
3, 4	C0, C1	I/O	Signal I/O (typically a differential pair)
5, 6	A2, A3	I/O	Signal I/O (typically a differential pair)
7, 8	C2, C3	I/O	Signal I/O (typically a differential pair)
10, 11	A4, A5	I/O	Signal I/O (typically a differential pair)
12, 13	C4, C5	I/O	Signal I/O (typically a differential pair)
14, 15	A6, A7	I/O	Signal I/O (typically a differential pair)
16, 17	C6, C7	I/O	Signal I/O (typically a differential pair)
22, 23	D7, D6	I/O	Signal I/O (typically a differential pair)
24, 25	B7, B6	I/O	Signal I/O (typically a differential pair)
26, 27	D5, D4	I/O	Signal I/O (typically a differential pair)
28, 29	B5, B4	I/O	Signal I/O (typically a differential pair)
31, 32	D3, D2	I/O	Signal I/O (typically a differential pair)
33, 34	B3, B2	I/O	Signal I/O (typically a differential pair)
35, 36	D1, D0	I/O	Signal I/O (typically a differential pair)
37, 38	B1, B0	I/O	Signal I/O (typically a differential pair)
9	SEL	I	Operation mode Select (when SEL=0: A→B, C→D, when SEL=1: A→D, B & C=Hi-Z)
18, 20, 30, 40, 42	V _{CC}	Pwr	1.8V positive supply voltage
19, 21, 39, 41	GND	Pwr	Power ground

Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-65°C to +150°C
Supply Voltage to Ground Potential.....	-0.5V to +2.5V
DC Input Voltage	-0.5V to V _{CC}
DC Output Current.....	120mA
Power Dissipation	0.5W

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics for Switching over Operating Range ($T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = 1.5\text{V}$ to 2.0V)

Paramenter	Description	Test Conditions	Min	Typ ⁽¹⁾	Max	Units
V _{IH}	Input HIGH Voltage	Guaranteed HIGH level	0.65 x V _{CC}			V
V _{IL}	Input LOW Voltage	Guaranteed LOW level	-0.5		0.35 x V _{CC}	
V _{IK}	Clamp Diode Voltage	V _{CC} = Max., I _{IN} = -18mA		-0.7	-1.2	
I _{IIH}	Input HIGH Current	V _{CC} = Max., V _{IN} = V _{CC}			±5	μA
I _{IIL}	Input LOW Current	V _{CC} = Max., V _{IN} = GND			±5	
R _{ON}	On Resistance	V _{CC} = Min., V _{IN} = 1.3V, I _{IN} = 40mA			10	Ohm
C _{ON(AB)}	Capacitance on A/B, C/D	V _{IN} = 0, V _{CC} = 1.8V		3.0		pF

Note:

1. Typical values are at $V_{CC} = 1.8\text{V}$, $T_A = 25^\circ\text{C}$ ambient and maximum loading.

Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
I _{CC}	Quiescent Power Supply Current	V _{CC} = Max., V _{IN} = GND or V _{CC}		200		μA

Notes:

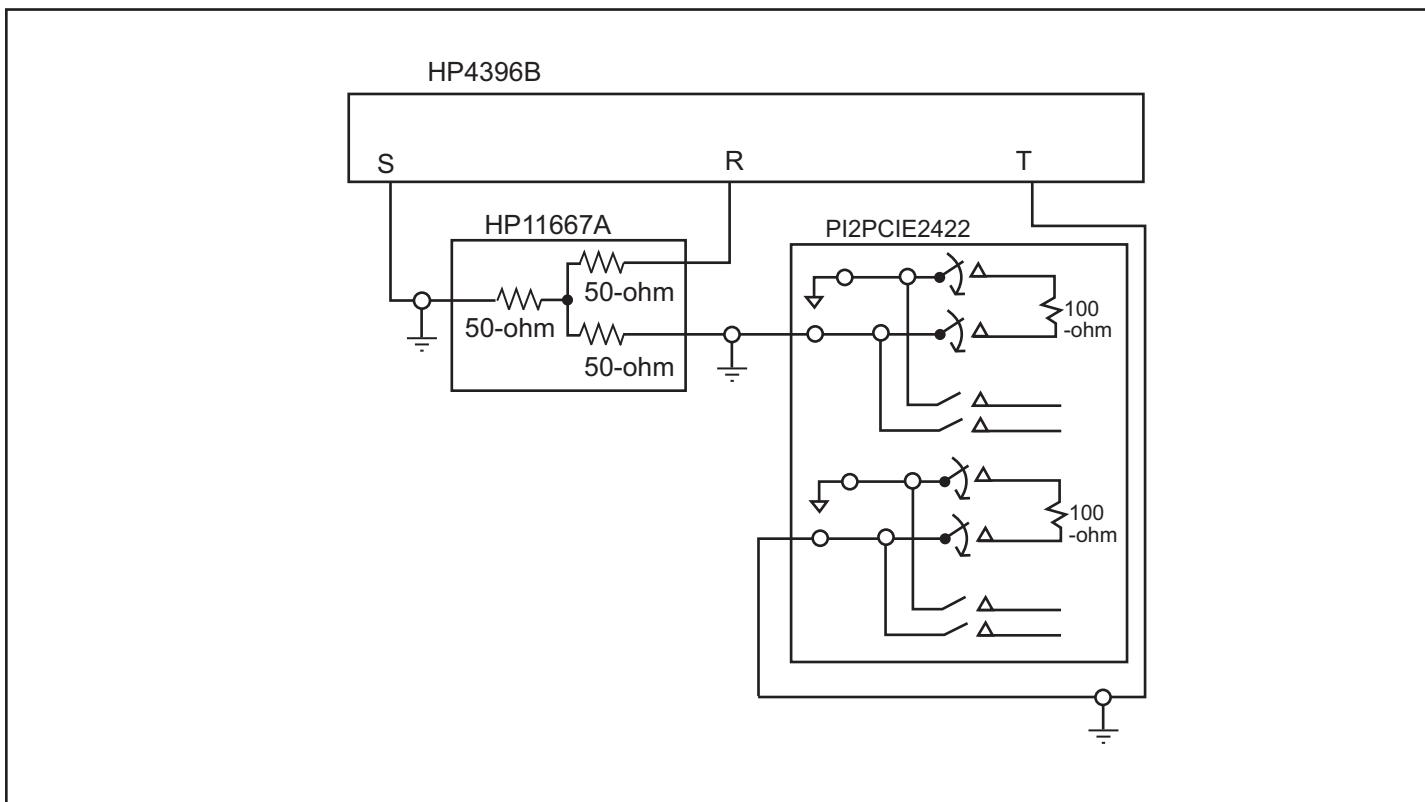
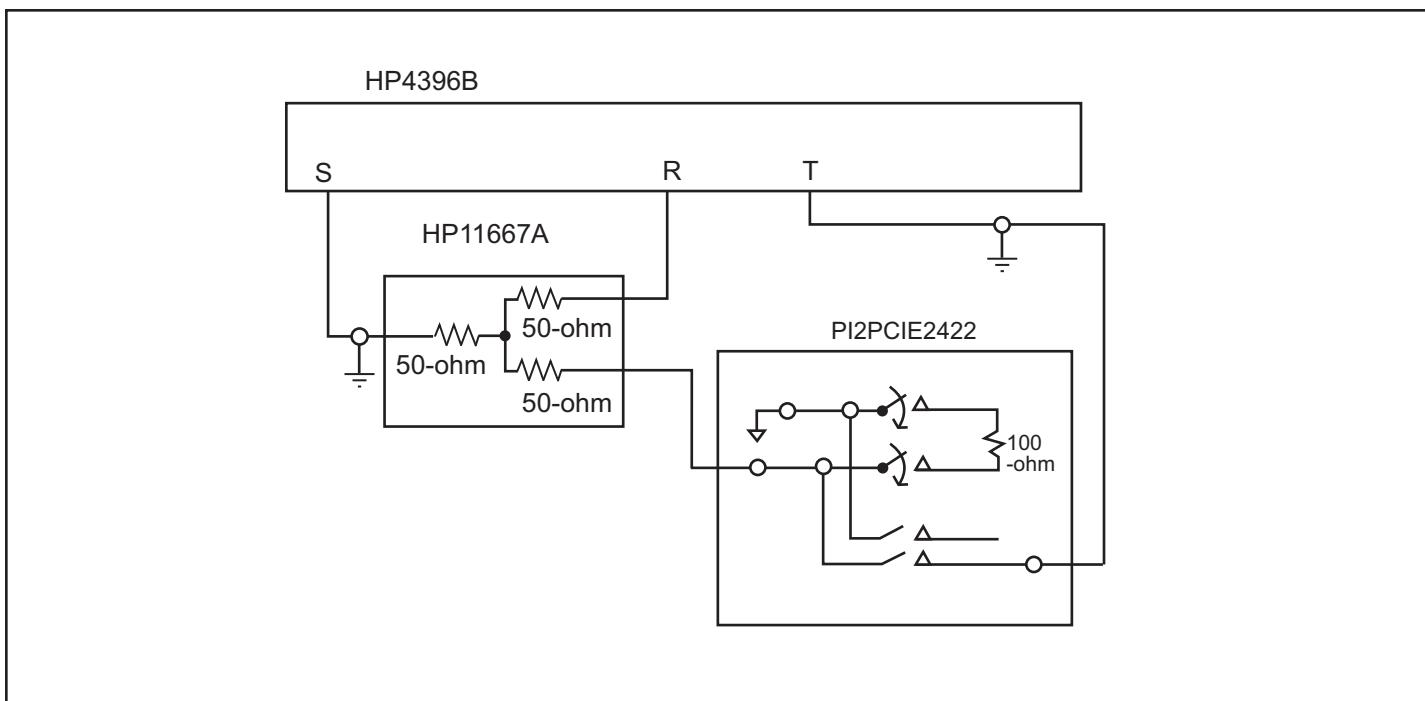
1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $V_{CC} = 1.8\text{V}$, $T_A = 25^\circ\text{C}$ ambient and maximum loading.

Dynamic Electrical Characteristics Over the Operating Range ($T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = 1.8\text{V} \pm 10\%$, GND=0V)

Parameter	Description	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Units
X _{TALK}	Crosstalk	See Fig. 1 for Measurement Setup, f = 3.00 GHz f = 100 MHz		-35 -70		dB
O _{IRR}	OFF Isolation	See Fig. 2 for Measurement Setup, f = 3.00 GHz f = 100 MHz		-26 -60		
I _{LOSS}	Differential Insertion Loss		f = 3 GHz	-3		
BW	Bandwidth (-3dB)			3.4		GHz

Notes:

1. Guaranteed by design. Typical values are at $V_{CC} = 1.8\text{V}$, $T_a = 25^\circ\text{C}$ ambient and maximum loading.


Fig 1: Crosstalk Setup

Fig 2: Off-isolation setup

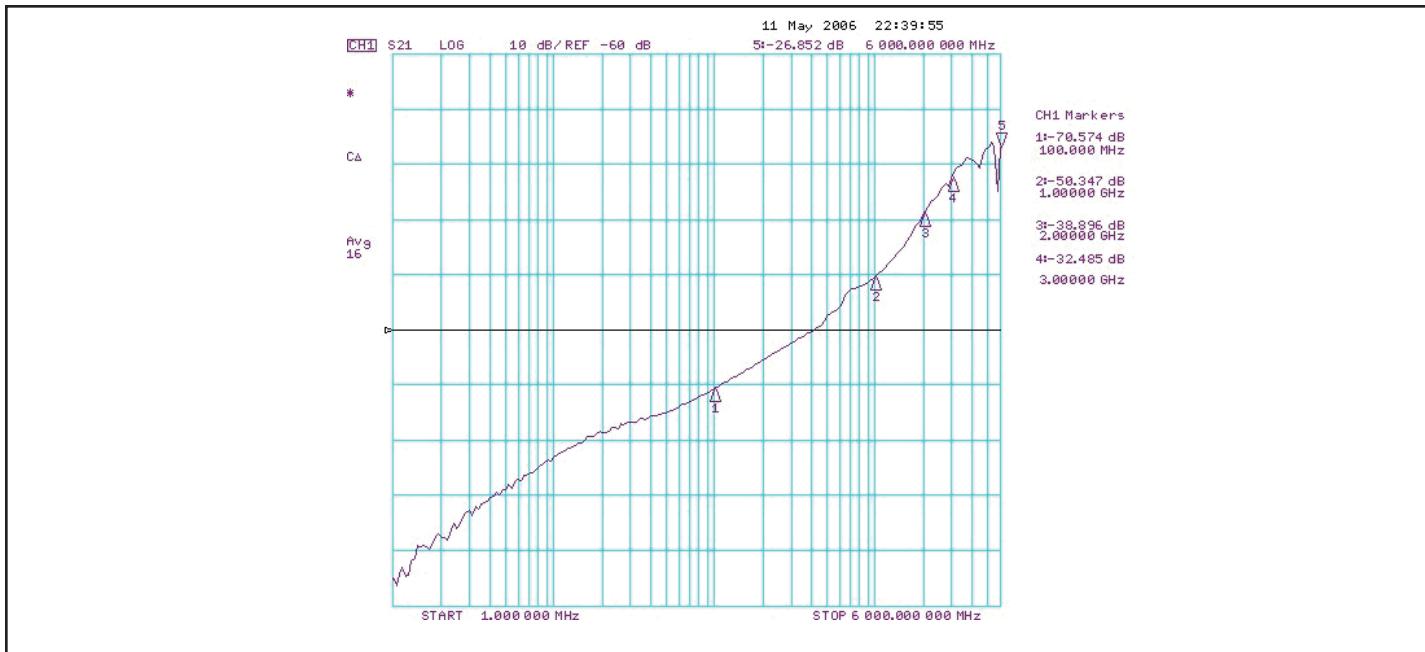


Fig 3: Typical Crosstalk Plot from 1MHz to 6.0GHz, Vcc=1.8V, 25°C

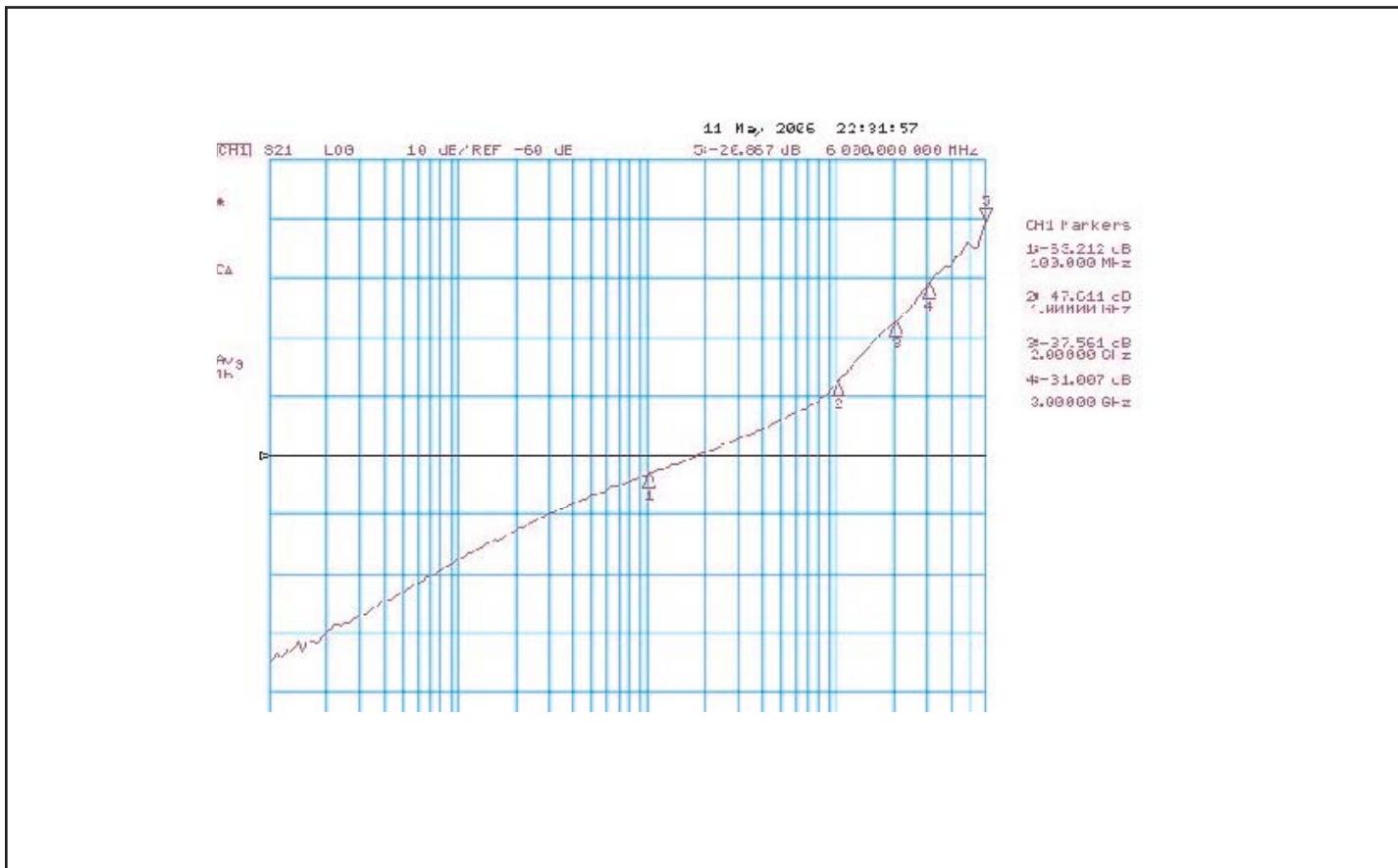


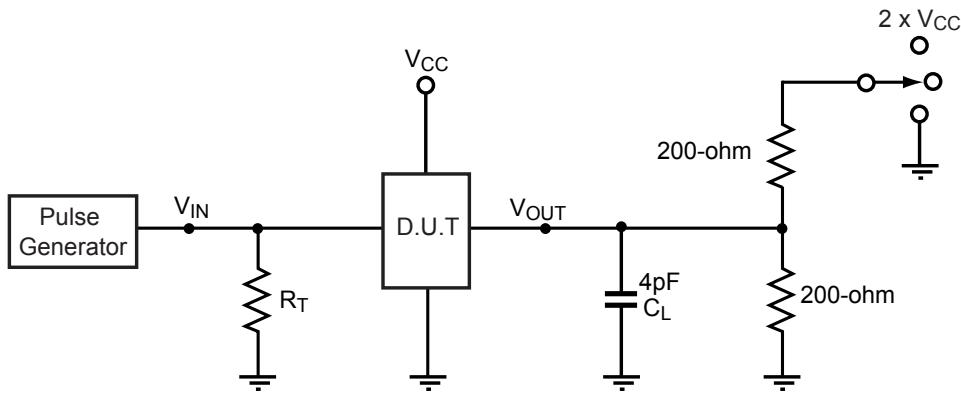
Fig 4: Typical Off Isolation Plot from 1 MHz to 6.0 GHz, VCC = 1.8V, TA=25°C



Fig 5: Typical Insertion Loss Plot from 1MHz to 6.0GHz, Vcc=1.8V, 25C

Switching Characteristics (T_A = -40° to +85°C, V_{CC} = 1.8V±10%)

Paramenter	Description	Min.	Typ.	Max.	Units
t _{PZH} , t _{PZL}	Line Enable Time - SEL to A _N , B _N	0.5		8.0	ns
t _{PHZ} , t _{PLZ}	Line Disable Time - SEL to A _N , B _N	0.5		8.0	
t _{b-b}	Bit-to-bit skew within same differential pair			4	ps
t _{ch-t_{ch}}	Channel-to-channel timing skew			35	

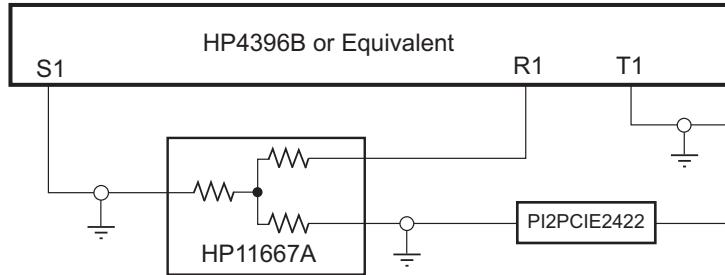
Test Circuit for Electrical Characteristics⁽¹⁾

Notes:

1. C_L = Load capacitance: includes jig and probe capacitance.
2. R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator
3. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
4. All input impulses are supplied by generators having the following characteristics: PRR ≤ MHz, Z_O = 50Ω, t_R ≤ 2.5ns, t_F ≤ 2.5ns.
5. The outputs are measured one at a time with one transition per measurement.

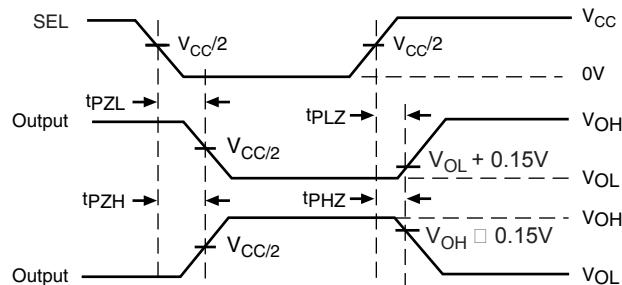
Switch Positions

Test	Switch
t _{PZL} , t _{PLZ} (output on B-side)	2 x V _{CC}
t _{PHZ} , t _{PZH} (output on B-side)	GND
Prop Delay	Open

Test Circuit for Dynamic Electrical Characteristics



Switching Waveforms



Voltage Waveforms Enable and Disable Times

Applications Information

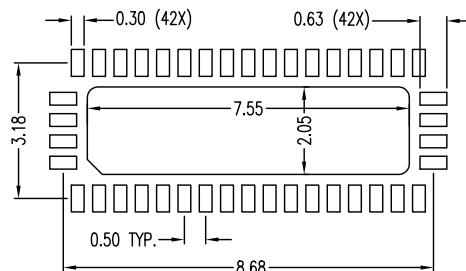
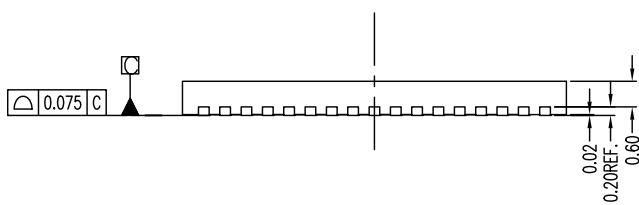
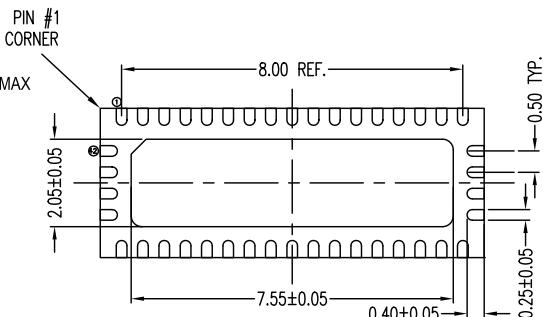
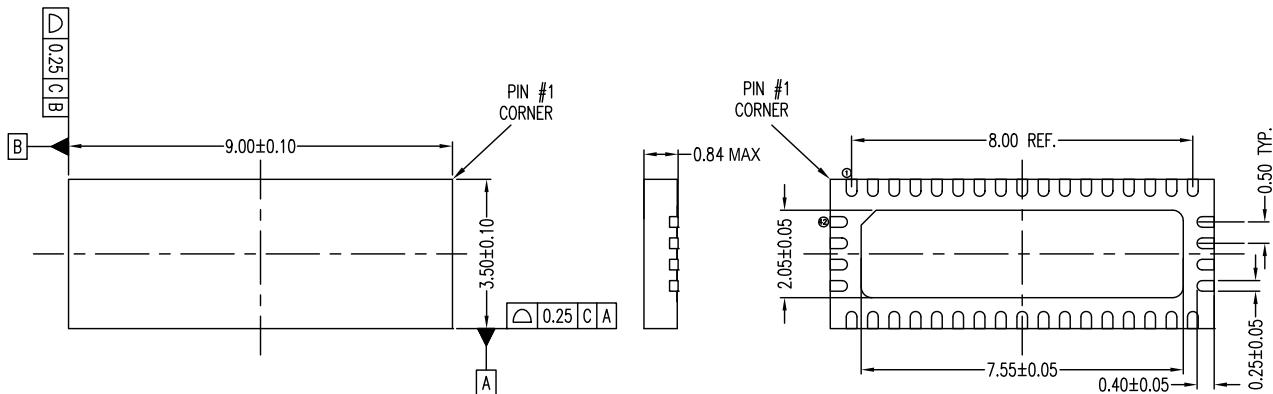
Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd

PCI Express Application Specific Measurements and Test Set-up

Figure 6: the test set-up for the PI2PCIE2422 eye test

Notes:

1. A modified PI2PCIE2422 application board with 16-inch differential trace is used for Eye management.
2. Agilent N4902B BERT is used to generate a K28.5 pattern at 5 Gbps with 500mV single-end swing.
3. To create the PI2PCIE2422-free test condition, the PI2PCIE2422 chip is removed and a wire is connected between the trace and output probe.
4. An Agilent Infinium 54855A is used and Serial Data Analysis software is ran to capture the Eye.



Recommended Land Pattern

NOTE :

1. ALL DIMENSION ARE IN mm. ANGLES IN DEGREES.
2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS. COPLANARITY SHALL NOT EXCEED 0.08 mm.
3. WARPAGE SHALL NOT EXCEED 0.10 mm.
4. REFER JEDEC MO-220 MODIFIED.
5. Thermal Via Diameter. Recommended 0.2~0.33mm
6. Thermal Via Pitch. Recommended 1.27mm



DATE: 03/10/06

DESCRIPTION: 42-contact Thin Fine Pitch Quad Flat No-Lead (TQFN)

PACKAGE CODE: ZH (ZH42)

DOCUMENT CONTROL #: PD-2035

REVISION: A

Ordering Information

Ordering Code	Package Code	Package Description
PI2PCIE2422ZHE	ZH	Pb-free and Green 42-contact TQFN

Notes:

1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
2. E = Lead-free and green
2. X suffix = tape and reel



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.